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THERMAL RESISTANCE RATINGS							
PARAMETER	SYMBOL	TYP.	MAX.	UNIT			
Maximum Junction-to-Ambient	R _{thJA}	-	62				
Case-to-Sink, Flat, Greased Surface	R _{thCS}	0.50	-	°C/W			
Maximum Junction-to-Case (Drain)	R _{thJC}	-	1.0				

PARAMETER	SYMBOL	TEST	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						•	,
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0$	0 V, I _D = 250 μA	1000	-	-	V
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	Reference	to 25 °C, I _D = 1 mA	-	1.4	-	V/°C
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V$	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$		-	4.0	V
Gate-Source Leakage	I _{GSS}	V _{GS} = ± 20 V		-	-	± 100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 1000 V, V _{GS} = 0 V		-	-	100	μΑ
Zero Gate Voltage Drain Gurrent		V _{DS} = 800 V, V _{GS} = 0 V, T _J = 125 °C		-	-	500	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} = 10 V	I _D = 1.9 A ^b	-	-	5.0	Ω
Forward Transconductance	9 _{fs}	V _{DS} = 1	0 V, I _D = 1.9 A ^b	2.1	-	-	S
Dynamic							
Input Capacitance	C _{iss}	٧	$V_{GS} = 0 V$,		980	-	
Output Capacitance	C _{oss}	V	_{DS} = 25 V,	-	140	-	pF
Reverse Transfer Capacitance	C _{rss}	f = 1.0	MHz, see fig. 5	-	50	-	
Total Gate Charge	Q_g		$V_{GS} = 10 \text{ V}$ $I_D = 3.1 \text{ A, } V_{DS} = 400 \text{ V, } - 400 \text{ V}$ see fig. 6 and 13b	-	-	80	nC
Gate-Source Charge	Q_{gs}	V _{GS} = 10 V		-	-	10	
Gate-Drain Charge	Q _{gd}			-	-	42	
Turn-On Delay Time	t _{d(on)}	$V_{DD} = 500 \text{ V, } I_D = 3.1 \text{ A}$ $R_g = 12 \Omega, R_D = 170 \Omega, \text{ see fig. } 10^b$		-	12	-	- ns
Rise Time	t _r			-	25	-	
Turn-Off Delay Time	t _{d(off)}			-	89	-	
Fall Time	t _f			-	29	-	
Internal Drain Inductance	L _D	Between lead, 6 mm (0.25") from package and center of die contact		-	4.5	-	- nH
Internal Source Inductance	L _S			-	7.5	-	
Drain-Source Body Diode Characteristic	s					•	,
Continuous Source-Drain Diode Current	I _S	MOSFET symbol showing the integral reverse p - n junction diode		=	-	3.1	- A
Pulsed Diode Forward Current ^a	I _{SM}			-	-	12	
Body Diode Voltage	V_{SD}	$T_J = 25 ^{\circ}\text{C}, I_S = 3.1 \text{A}, V_{GS} = 0 \text{V}^{\text{b}}$		-	-	1.8	V
Body Diode Reverse Recovery Time	t _{rr}	– T _J = 25 °C, I _F = 3.1 A, dl/dt = 100 A/μs ^b		-	410	620	ns
Body Diode Reverse Recovery Charge	Q_{rr}			-	1.3	2.0	μC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by L_S and L_D)				L _D)	

Notes

- a. Repetitive rating; pulse width limited by maximum junction temperature (see fig. 11).
- b. Pulse width \leq 300 μ s; duty cycle \leq 2 %.



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

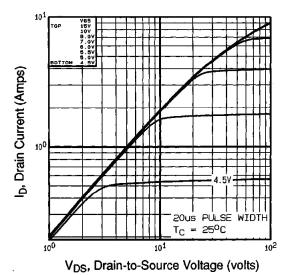


Fig. 1 - Typical Output Characteristics, $T_C = 25$ °C

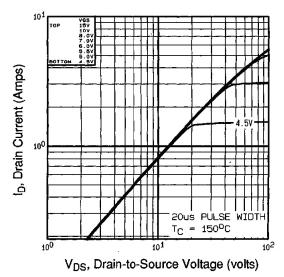


Fig. 2 - Typical Output Characteristics, $T_C = 150$ °C

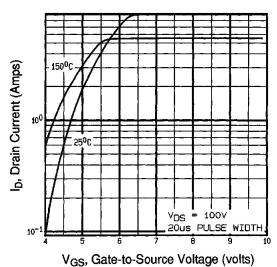


Fig. 3 - Typical Transfer Characteristics

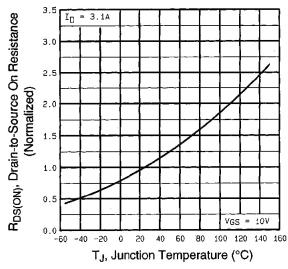


Fig. 4 - Normalized On-Resistance vs. Temperature

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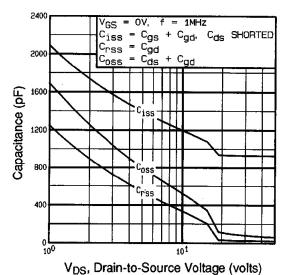


Fig. 5 - Typical Capacitance vs. Drain-to-Source Voltage

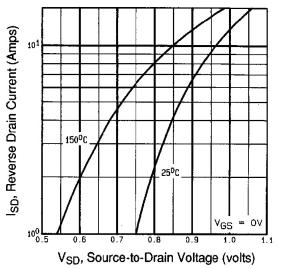


Fig. 7 - Typical Source-Drain Diode Forward Voltage

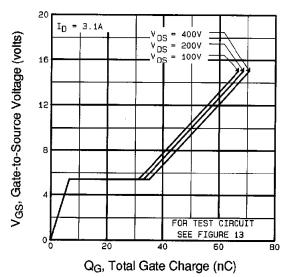


Fig. 6 - Typical Gate Charge vs. Gate-to-Source Voltage

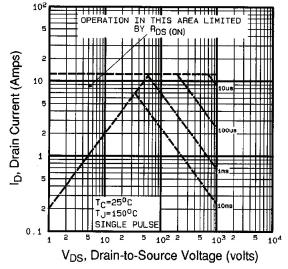


Fig. 8 - Maximum Safe Operating Area





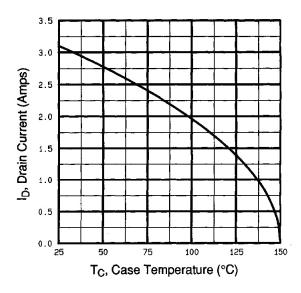


Fig. 9 - Maximum Drain Current vs. Case Temperature

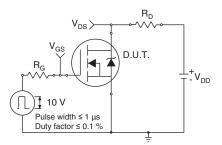


Fig. 10a - Switching Time Test Circuit



Fig. 10b - Switching Time Waveforms

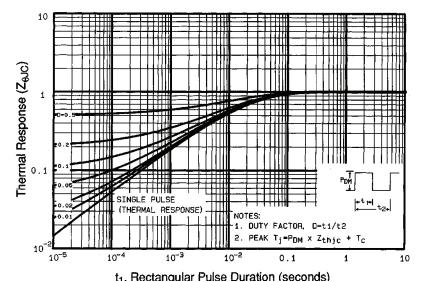


Fig. 11 - Maximum Effective Transient Thermal Impedance, Junction-to-Case

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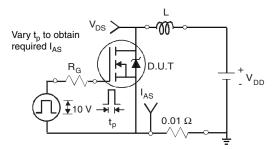


Fig. 12a - Unclamped Inductive Test Circuit

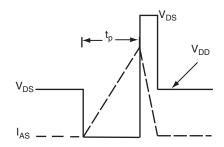


Fig. 12b - Unclamped Inductive Waveforms

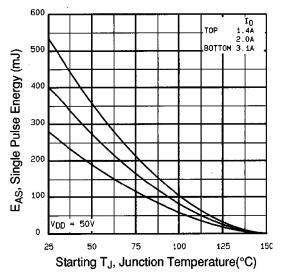


Fig. 12c - Maximum Avalanche Energy vs. Drain Current

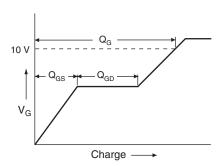


Fig. 13a - Basic Gate Charge Waveform

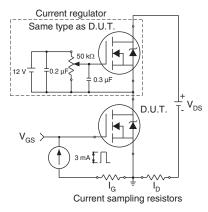
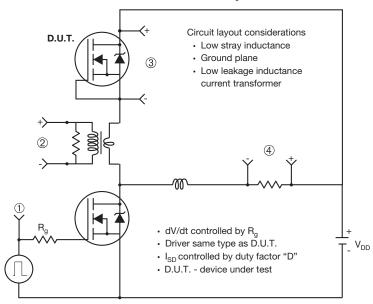


Fig. 13b - Gate Charge Test Circuit



Peak Diode Recovery dV/dt Test Circuit



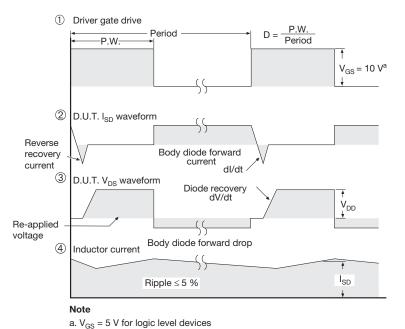


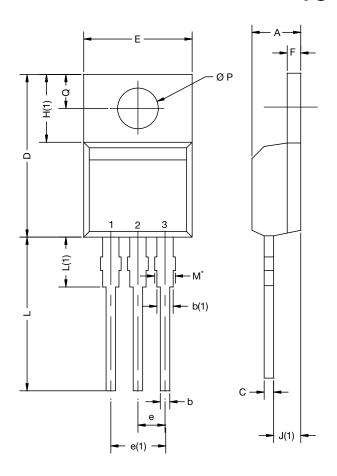
Fig. 14 - For N-Channel

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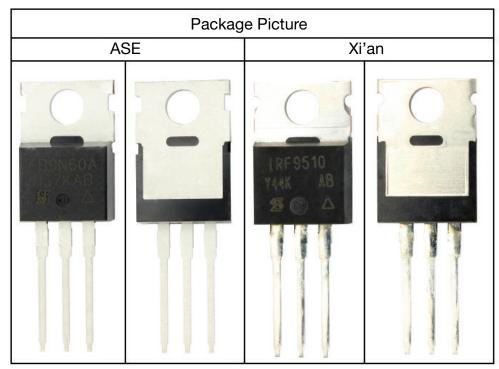
TO-220-1



DIM.	MILLIM	IETERS	INCHES		
	MIN.	MAX.	MIN.	MAX.	
Α	4.24	4.65	0.167	0.183	
b	0.69	1.02	0.027	0.040	
b(1)	1.14	1.78	0.045	0.070	
С	0.36	0.61	0.014	0.024	
D	14.33	15.85	0.564	0.624	
E	9.96	10.52	0.392	0.414	
е	2.41	2.67	0.095	0.105	
e(1)	4.88	5.28	0.192	0.208	
F	1.14	1.40	0.045	0.055	
H(1)	6.10	6.71	0.240	0.264	
J(1)	2.41	2.92	0.095	0.115	
L	13.36	14.40	0.526	0.567	
L(1)	3.33	4.04	0.131	0.159	
ØΡ	3.53	3.94	0.139	0.155	
Q	2.54	3.00	0.100	0.118	
ECN: X15-0364-Rev. C, 14-Dec-15 DWG: 6031					

Note

 \bullet $M^{\star}=0.052$ inches to 0.064 inches (dimension including protrusion), heatsink hole for HVM



Revison: 14-Dec-15 1 Document Number: 66542

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